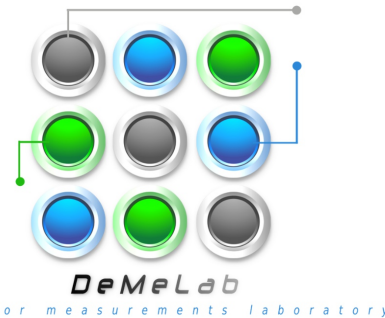


Critical component degradation and in-flight calibration of EUI onboard Solar Orbiter

Talk outline

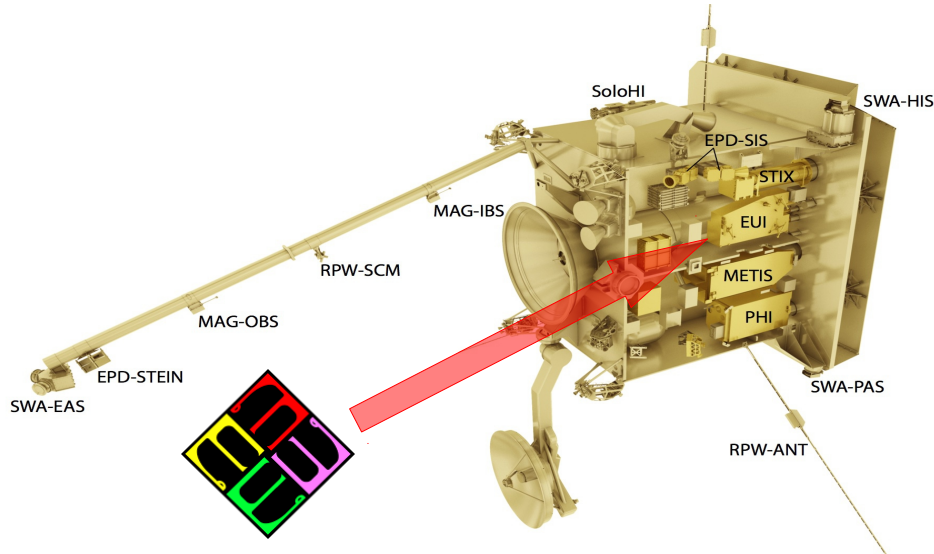
- 1 Introduction to Solar Orbiter mission and environment
- 2 The EUI instrument & degradation: detector, filter, LED
- 4 Cleanliness & contamination
- 5 Conclusions



Samuel Gissot, Boris Giordanengo and Ali BenMoussa

- 1 - Solar-Terrestrial Center of Excellence (STCE) - 2 - Royal Observatory of Belgium (ROB)

Solar Orbiter S/C overview

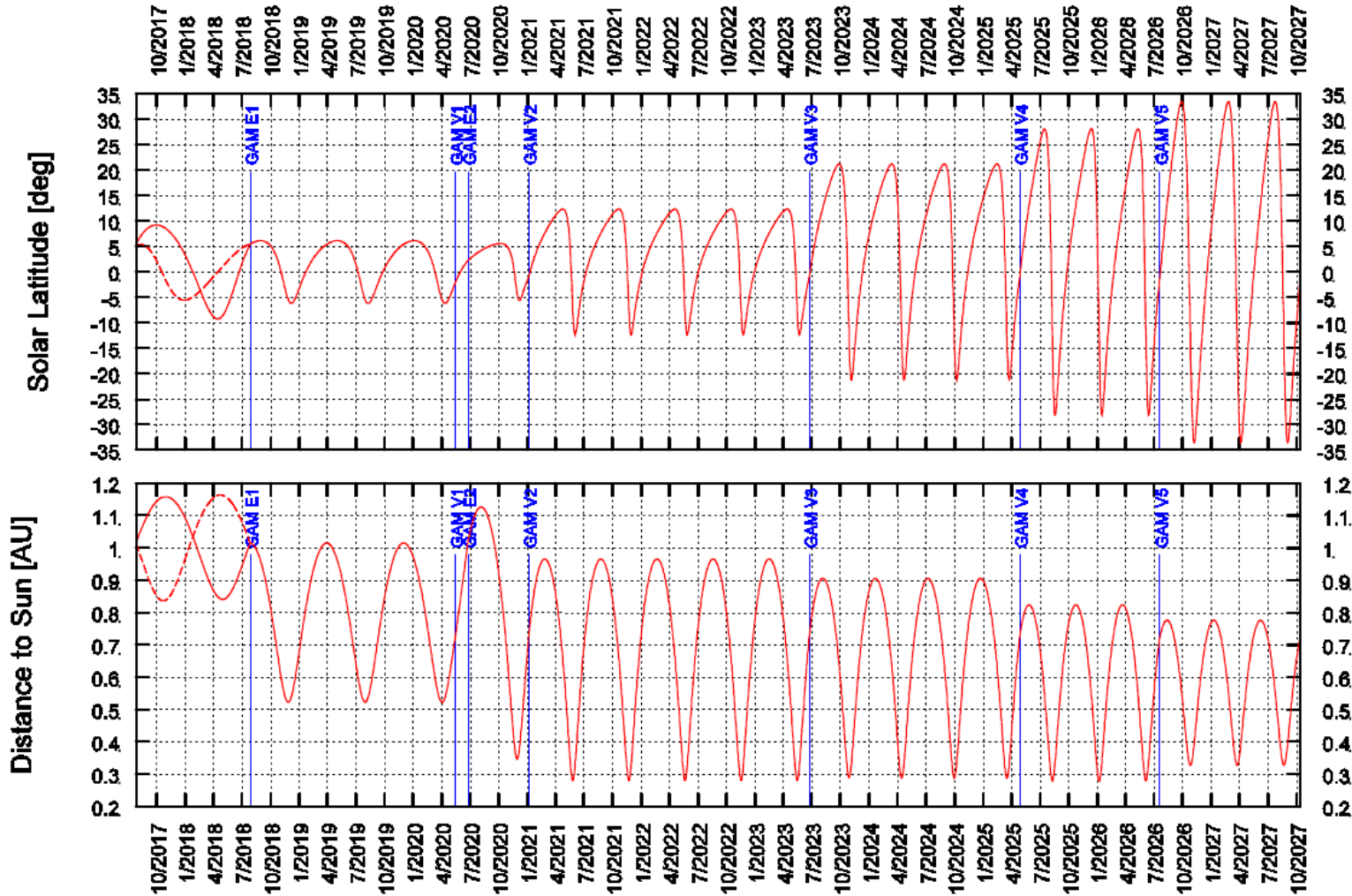


10 instruments:

- 6 Remote-sensing instruments operational during 3 x 10 day science windows per orbit
- 4 In-situ instruments operational continuously

- Current launch date (baseline): July 2017 on Ariane 5
- Highly eccentric orbit around the Sun
- 3 year Cruise Phase:
 - Gravity Assist Manoeuvres at Venus & Earth to reach operational orbitNominal Mission = 3.5 years,
Extended Mission = 3 years
- Daily ground contact (except for conjunction periods, longest = 61 days)

S/O mission profile and orbits (July 2017 launch)



S/O mission profile and orbits

- SO S/C will approach the Sun 12 times below 0.3 AU and 16 times below 0.4 AU in an overall duration of 10.2 years.
- The duration that the spacecraft will stay below these distances is 102 and 406 days, respectively.
- High temperature variations
 - Increased outgassing
- High fluxes UV, e⁻, p⁺ :
 - Increased degradation of materials
 - Increased photo-deposition

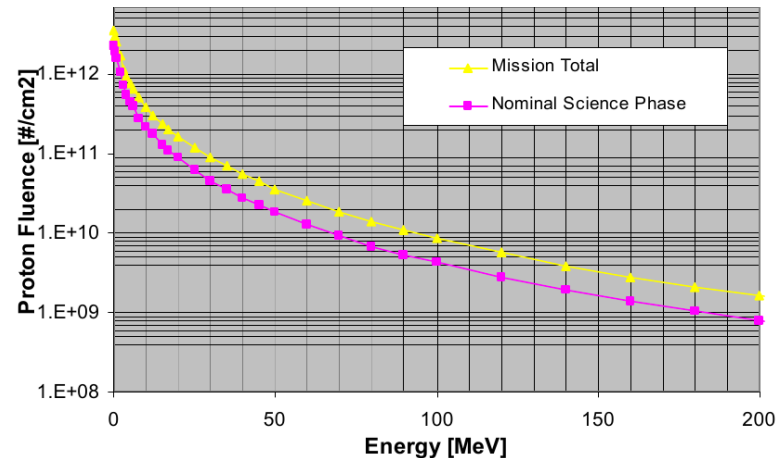
Solar Orbiter Environment: main characteristics

Solar and Planetary Electromagnetic Radiation (EUV)

Type	Wavelength (nm)	At the Earth's distance		Solar Orbiter Mission	
		Average Flux (W/m ²)	Worst-Case Flux (W/m ²)	Average Flux (W/m ²)	Worst-Case Flux (W/m ²)
Near UV	180-400	118	177	323	2250
UV	< 180	2.3×10^{-2}	4.6×10^{-2}	6.3×10^{-2}	0.6
UV	100-150	7.5×10^{-3}	1.5×10^{-2}	2.1×10^{-2}	0.2
EUV	10-100	2×10^{-3}	4×10^{-3}	5×10^{-3}	5×10^{-2}
X-Rays	1-10	5×10^{-5}	1×10^{-4}	1.4×10^{-4}	1×10^{-3}
Flare X-Rays	0.1-1	1×10^{-4}	1×10^{-3}	3×10^{-4}	1×10^{-2}

Energetic Particle Radiation

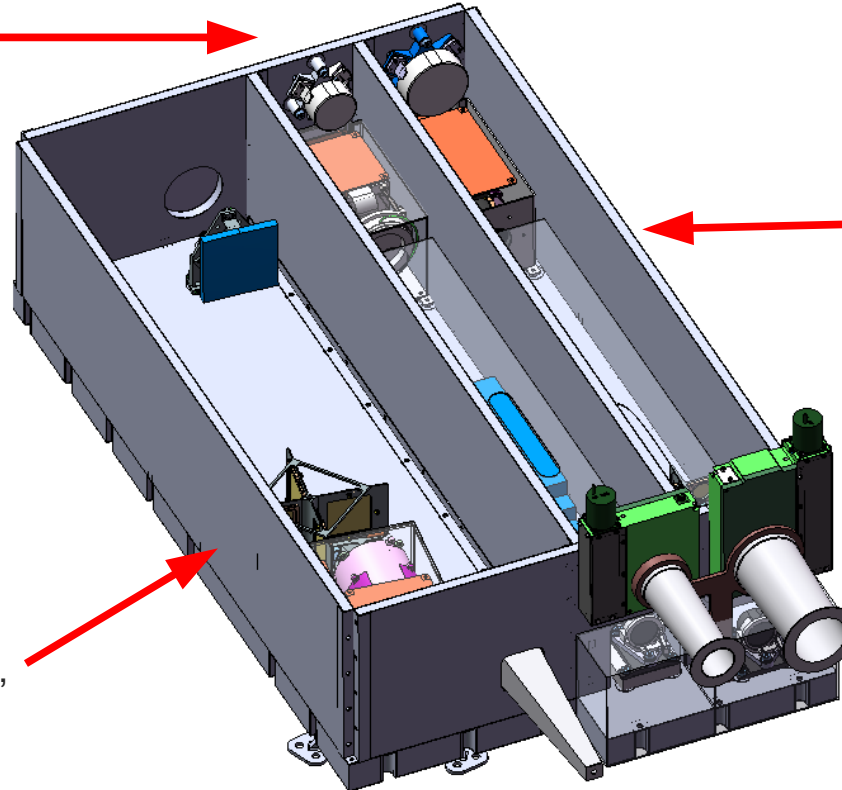
- Total mission proton fluence: 1-4 e11 p+/cm²
- TID: 150 krad [Si]



EUI-OBS unit overview & channel specificities

High Resolution Imager (HRI/Ly- α)

- 121.6 nm
- 1 arcsec resolution (2kx2k, 10 μ m pix)
- 1-2 s cadence



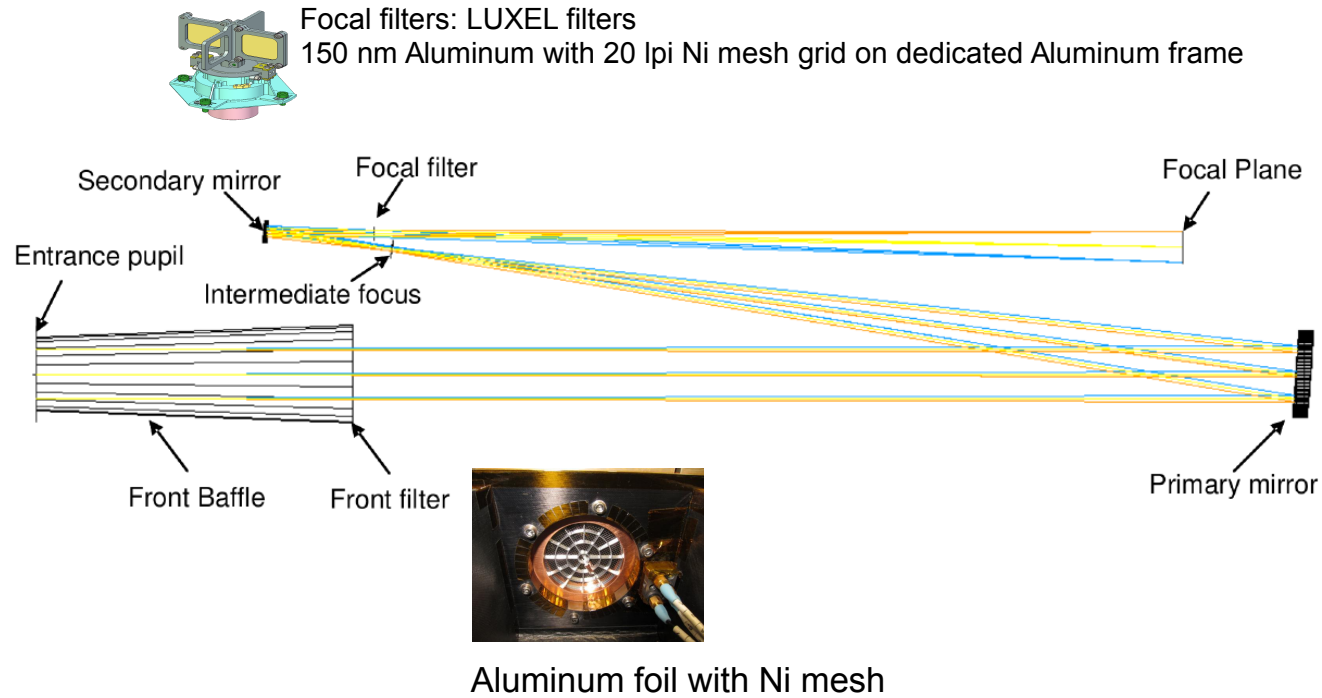
High-Resolution Imager (HRI/EUV)

- 17.4 nm
- 1 arcsec resolution (2kx2k, 10 μ m pix)
- 1-2 s cadence
- Low photon flux (limited by small aperture)

Full-Sun Imager (FSI)

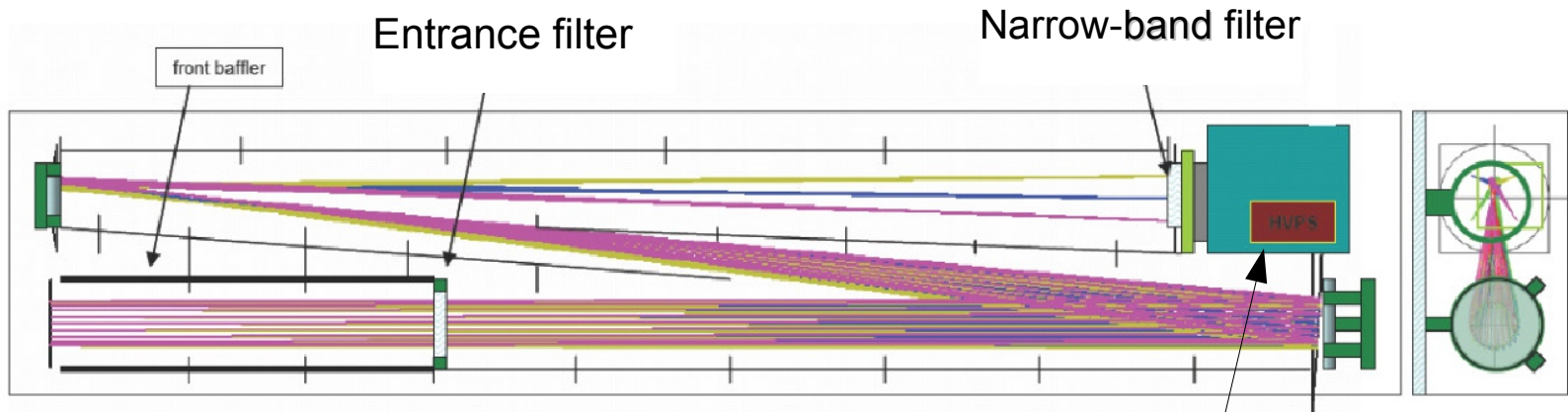
- Dual-band 17.4 / 30.4 nm
- 9 arcsec resolution (3kx3k, 10 μ m pix)
- min 10 s cadence

HRI-EUV



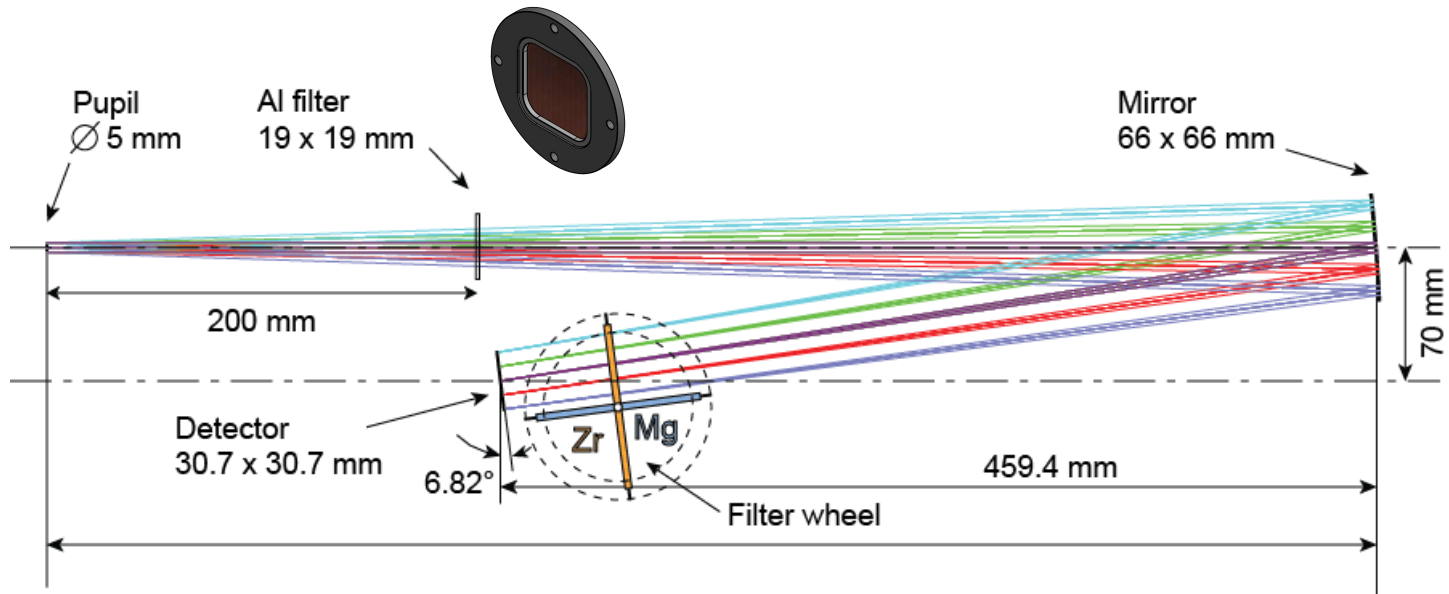
- Based on an off-axis Gregory telescope optimized in length and width
- entrance baffle reduces the heat input reaching the entrance foil filter

HRI-Ly α



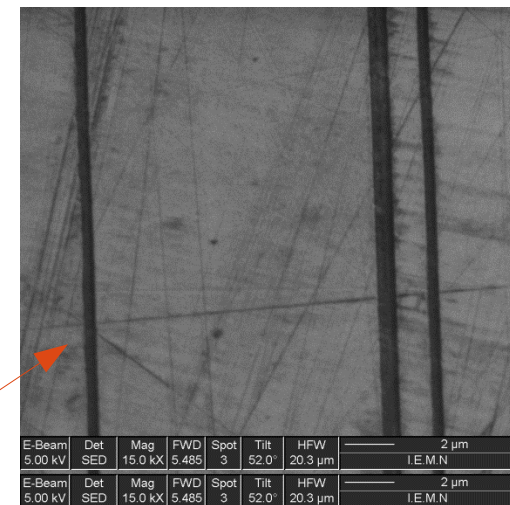
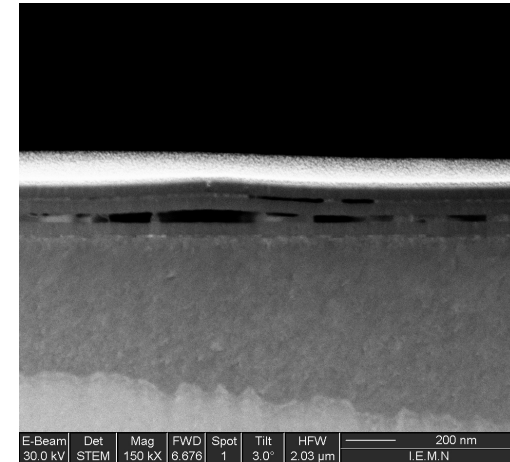
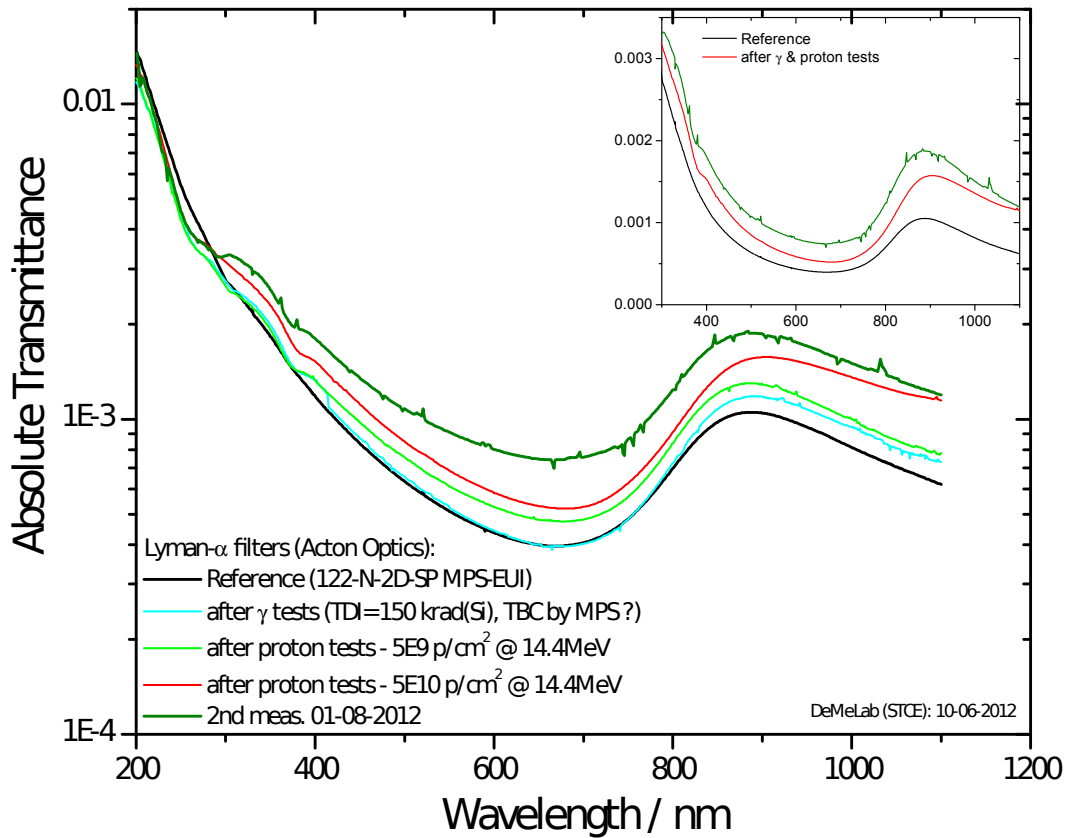
- HRI-Lya Entrance Filter from ACTON Optics & Coatings, type FN-122-N, now procured by Pelham.
- “open-faced” filter having the interference coating on one side of the MgF2 substrate
- MCP & High-voltage units
- FPA: APSOLUTE front-side detector

Full-Sun Imager



- FSI unit is based on a Herschelian telescope optimized with a 5 mm diameter aperture pupil located at the front section of the FSI entrance baffle.
- Entrance filter: LUXEL filter
 - Custom frame
 - Hexagonal mesh
- Multilayer structure on filter wheel
 - Al/Zr/Al
 - Al/Mg/Al

HRI-Ly- α entrance filter after proton fluence irradiation

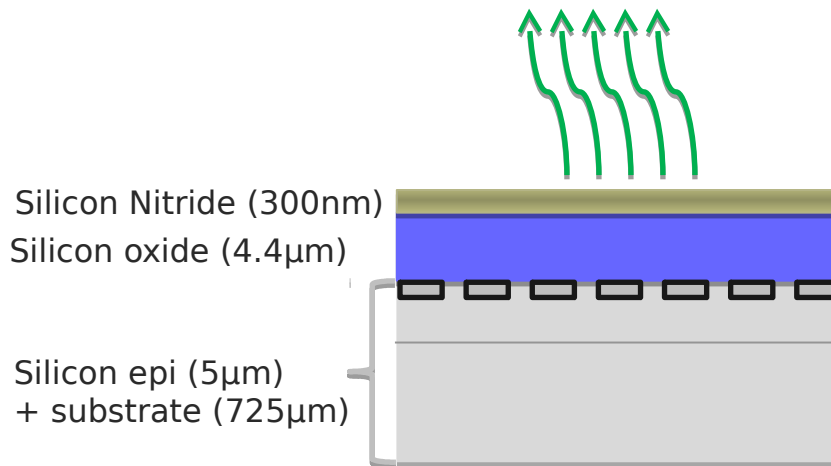


SEM: cracks observed on Al top coating may explain the increase of the visible transmission after proton irradiation.

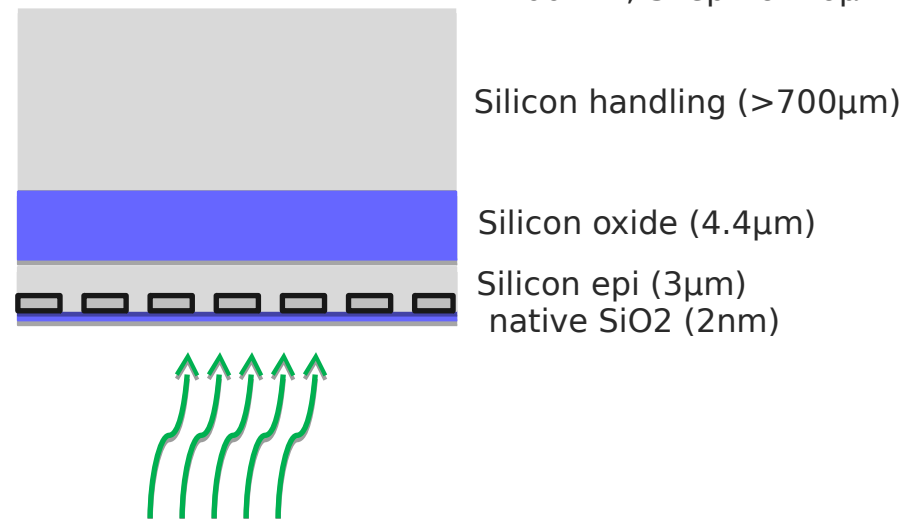
BSI vs FSI image sensors

- Provided by CMOSIS sub-contractor
- Test chip (Monolithic) on SOI (SOITEC) material, 0.18 μm technology (TS)
- 10 μm pixel pitch pinned photodiode (PPD) based on 4T pixel design
- Thinned (250 and 400nm etch) for back-side illumination optimized for EUV sensitivity
- Dual-gain pixel read out

Front side imagers (FSI)



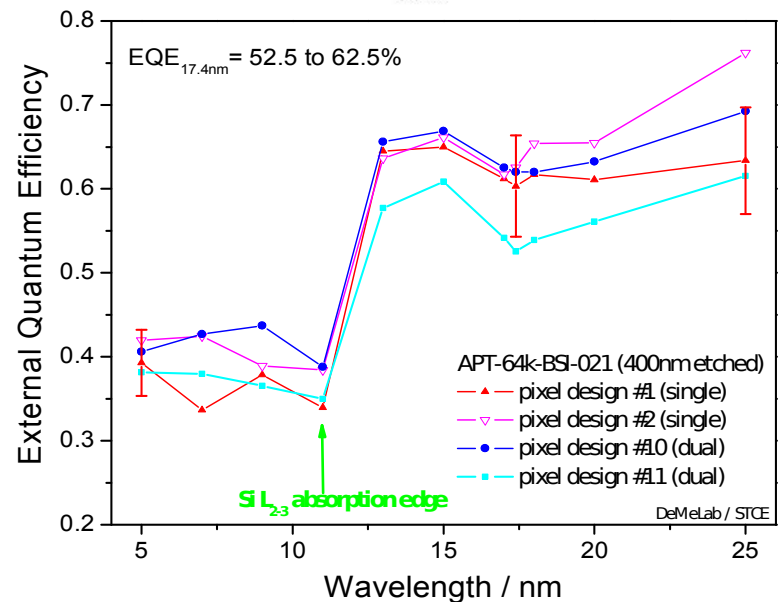
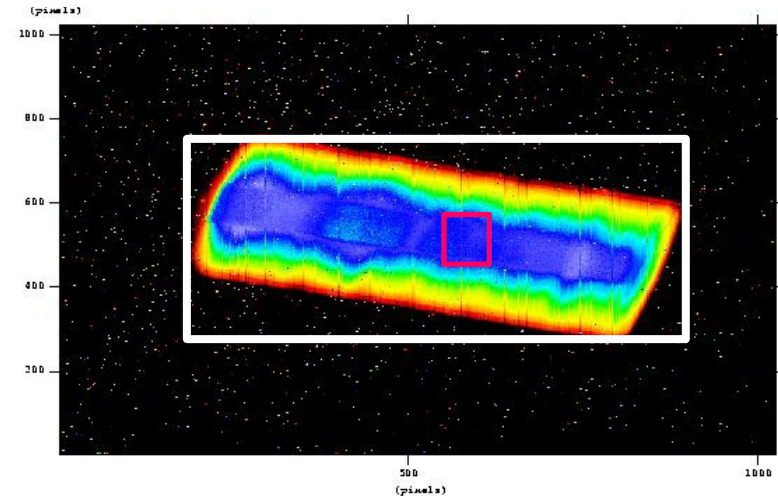
Back side imager (BSI), Baseline



Remark: BSI are etched to:
- 250 nm ; Si epi to 2.75 μm
- 400nm ; Si epi to 2.6 μm

Detector and instrument-level calibration measurements

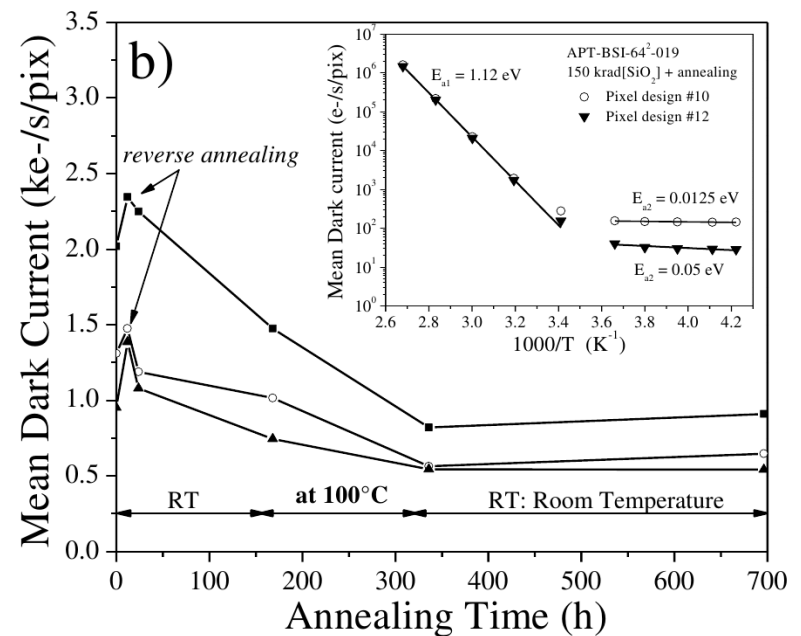
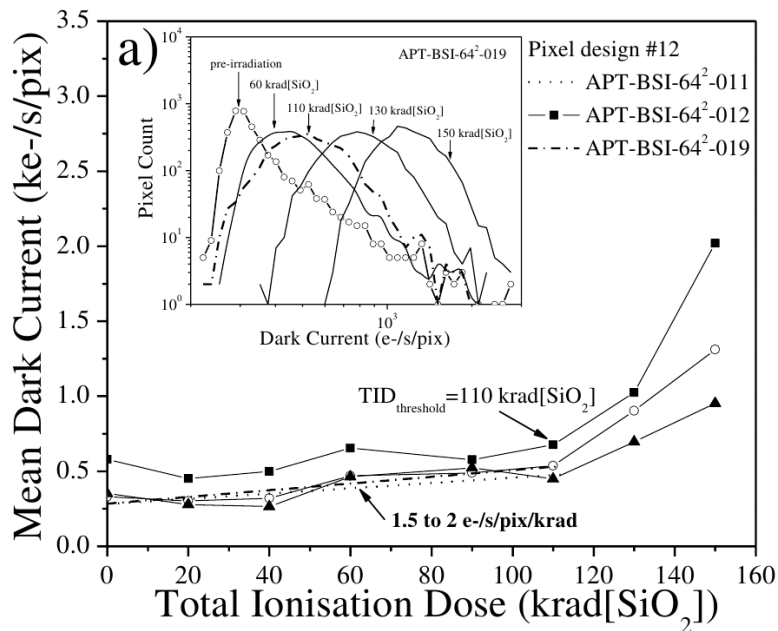
- APSOLUTE-1 & 2 parameters to estimate [Requirements]
 - Visible
 - Dual gains
 - Full Well [$> 80 \text{ ke-}$]
 - Linearity
 - Visible(LED)-to-EUV degradation mapping
 - EUV
 - EQE [$>50\%$] measured at PTB/BESSY-II
 - Lag & Stability
 - Flat field (challenging)
 - Dark measurements
 - DC, FPN offsets, Read Noise [$<5 \text{ e-}$]
 - Robustness to SO environment
 - TID with γ and $p+$ [$>100 \text{ krad [Si]}$]
 - Displacement damages
 - Used for best pixel design selection



APSOOLUTE-I detector degradation

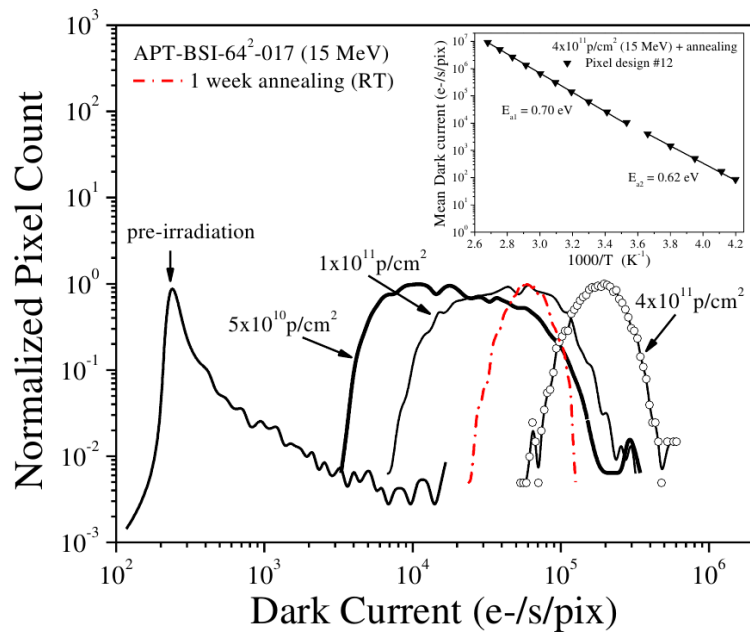
TID effects on Dark Current

Annealing; recovery after 2 week at RT



APSOOLUTE-I detector degradation (2)

Displacement damage effects on DC

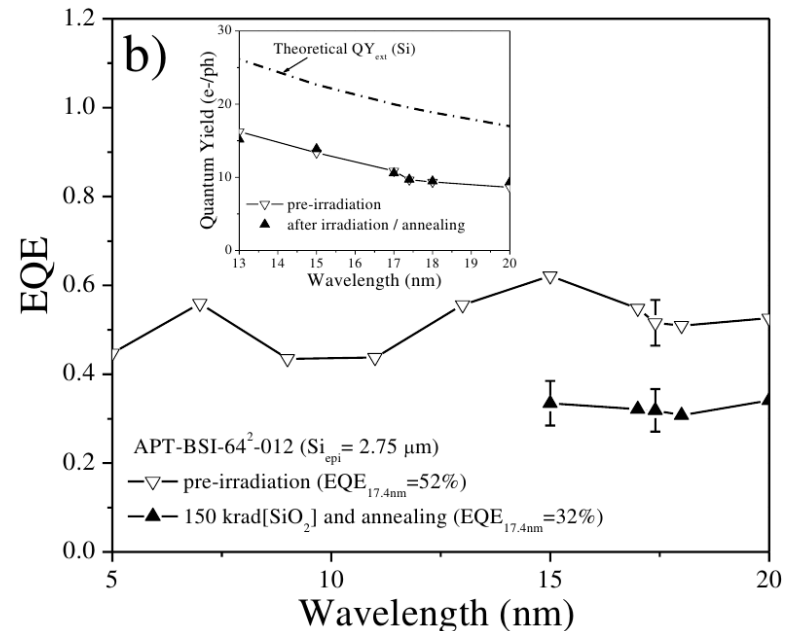
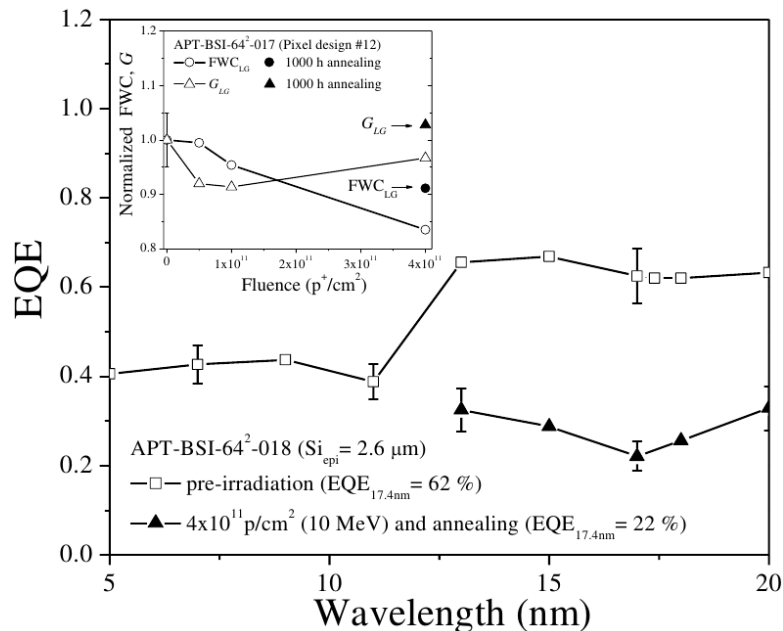


- No full DC recovery
- Permanent damages

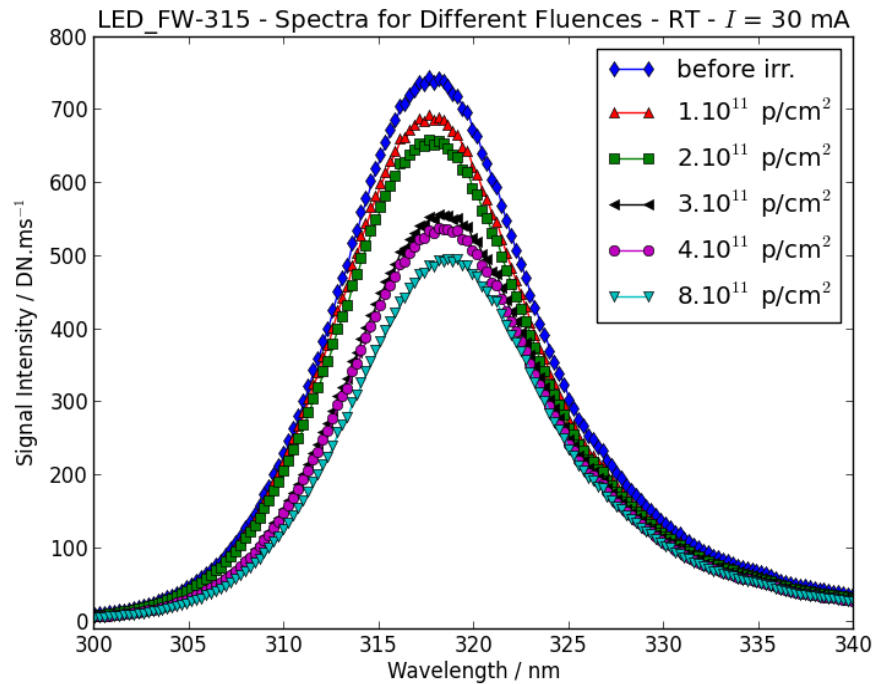
APSOOLUTE-I detector degradation (3)

Displacement damage effects on EQE

TID on EQE (permanent damages)



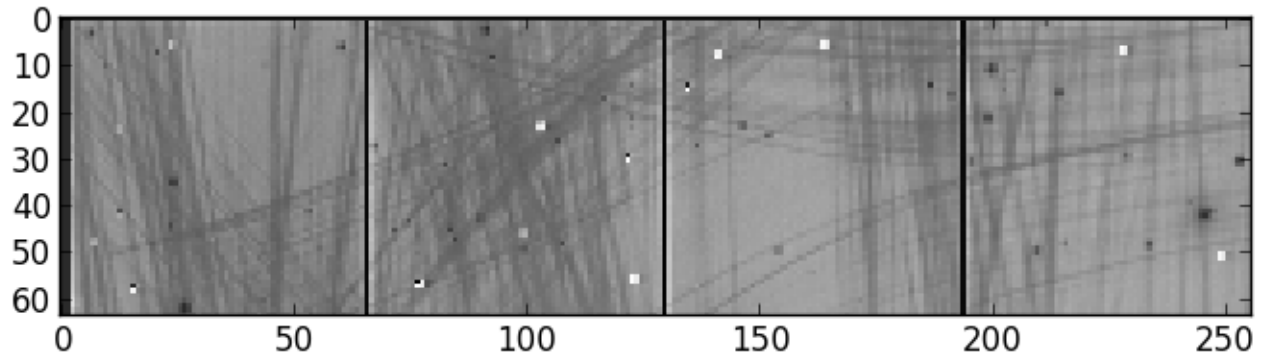
Onboard calibration LEDs degradation tests



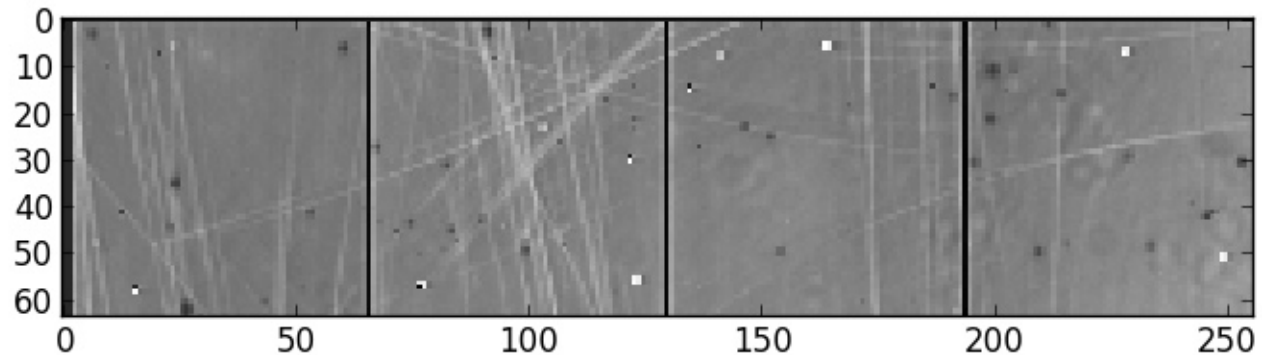
- Robustness against proton irradiation
- Used for flat-field computation, to be compared with ground EUV flat-fields
- Visible LED used on-board

[LEDs (2): wavelength-dependance]

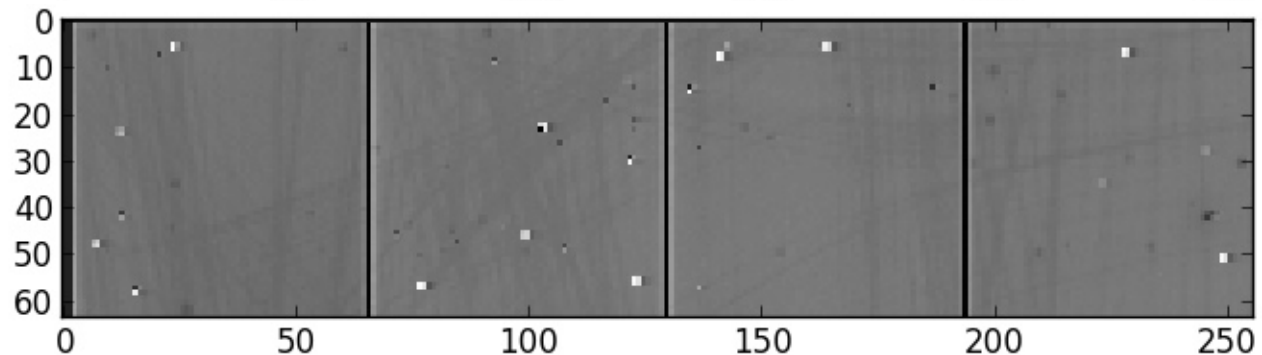
BSI 64K imager
illuminated with
LED_FW-315 nm from
SETI
with a forward current
 $I_F = 50$ mA



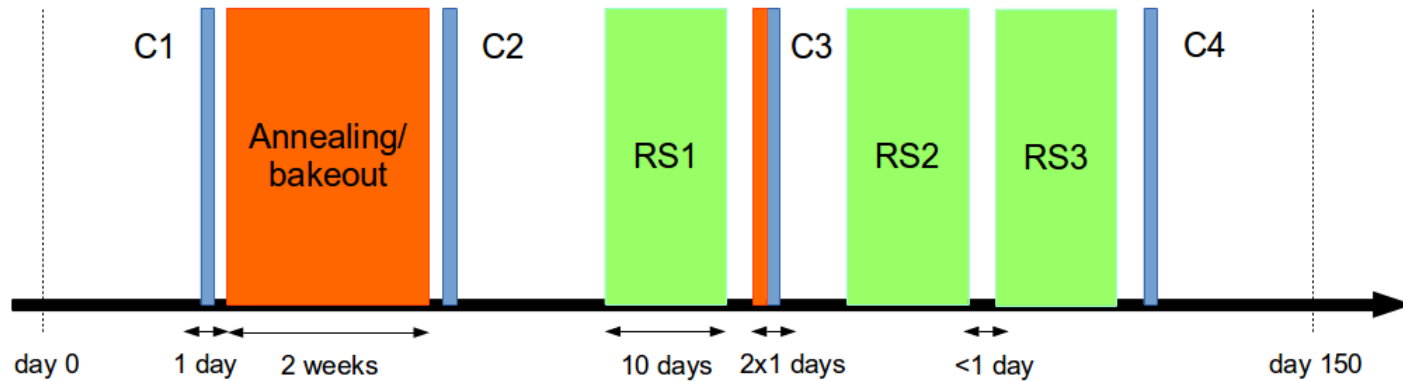
Same with LED_FW-
355 nm from SETI



Same with 62621 LED
from Micropac,
forward current $I_F = 0.1$
mA



EUI orbit profile & duty cycle



- Onboard calibration campaigns: EUI will perform pre-(lossy)compression calibration autonomously
 - Flat-field and dark offsets onboard update (requires approval by EUI operator)
 - Implemented on-board only if high relative difference are detected in calibration products.
 - Off-pointing (and rolls) manoeuvres for inflight EUV flat field estimations
- C1,C2: annealing efficiency assessment
- Degradation monitoring:
 - Dark current
 - Full Well
 - RTS pixels

Cleanliness/contamination

- Careful contamination control (Solar Orbiter Cleanliness WG led by U. Schühle, MPS)
- EUI sensitive areas on optical-path:
 - Entrance filter (2 surfaces)
 - Mirrors (2 surfaces for HRI, 1 for FSI)
 - Focal plane filter (2 surfaces)
 - Detector entrance window (1 surface)

Cleanliness of EUI at S/C delivery

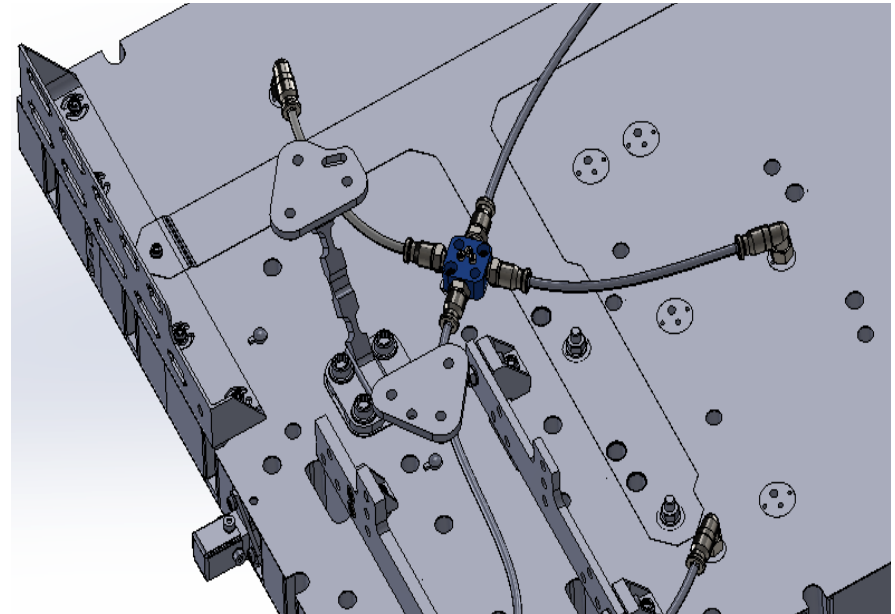
- Limitations of contamination on EUI sensitive areas

Sensitive Area	Limit molecular [ng/cm ²]		Limit: particulate [ppm]	
	Delivery	EOL	Delivery	EOL
Entrance baffle	50	370	54	300
Mirrors, filters, internal surfaces	50	370	54	100
External H/W (MLI, E-Box)	100	370	100	300

- The Entrance Filter is the first critical optical element of the EUI telescopes
 - permanently exposed to solar irradiation during orbit
 - strong UV radiation that can lead to polymerization of organic contaminants.
- Purging procedures
 - Gas (N₂) quality grade control
 - Purging flow rate control to avoid damage (limited ΔP) on foil filters
 - Repressurization of vacuum chamber after bake-out
- Particular and molecular witness samples (PFO, witness plates)
 - to monitor cleanliness cleanliness at all AIT activities (after assembly, vibration, vacuum/bakeout tests...)

Purge system requirements

- “after EUI delivery almost continuous purging of the EUI structural housing with clean and dry nitrogen gas until launch. “
- “longest duration **without purging shall be limited to 30 minutes per any 24 hours**, except during the vacuum tests sequences.”
- “ For the purging to be interrupted, the external environment shall be equivalent to ISO class 8 with a relative humidity of $55 \pm 10\%$.”



Conclusion

- EUI just passing CDR
- ROB-DeMeLab working on EUI subsystems (detectors, filters, LEDs) and inflight calibration
- Thank you !